

Structural and dynamical properties of liquid Si. An orbital-free molecular dynamics study

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Several static and dynamic properties of liquid silicon near melting have been determined from an orbital free *ab-initio* molecular dynamics simulation. The calculated static structure is in good agreement with the available X-ray and neutron diffraction data. The dynamical structure shows collective density excitations with an associated dispersion relation which closely follows recent experimental data. It is found that liquid silicon can not sustain the propagation of shear waves which can be related to the power spectrum of the velocity autocorrelation function. Accurate estimates have also been obtained for several transport coefficients. The overall picture is that the dynamic properties have many characteristics of the simple liquid metals although some conspicuous differences have been found.

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I. INTRODUCTION.

Molecular dynamics (MD) methods are a useful technique to study the properties of liquid systems, and the last two decades have witnessed a large increase in the application of *ab-initio* molecular dynamics methods (AIMD) based on the density functional theory¹ (DFT) for the treatment of the electron system. This theory allows calculation of the ground state electronic energy of a collection of atoms, for given nuclear positions, and also yields the forces on the nuclei via the Hellmann-Feynman theorem. It allows MD simulations in which the nuclear positions evolve according to classical mechanics with the electronic subsystem following adiabatically. Most AIMD methods are based on the Kohn-Sham (KS) orbital representation of the DFT (KS-AIMD methods) which, at present, poses heavy computational demands which limit the size of the systems that can be studied as well as the simulation times. However, some of these constraints are eased in the so-called orbital-free *ab-initio* molecular dynamics (OF-AIMD) method, which by disposing of the electronic orbitals of the KS formulation provides a simulation method where the number of variables describing the electronic state is greatly reduced, enabling the study of larger samples (several hundreds of particles) and for longer simulation times (tens of ps).

This paper reports the results of an *ab-initio* molecular dynamics simulation on the static and dynamic properties of liquid Silicon (l-Si) at thermodynamic conditions near its triple point. Si is an interesting material with many peculiar properties which, along with its technological importance, has stimulated intensive theoretical^{2,3,4,5,6,7,8,9} and experimental^{10,11,12,13,14,15} work. Its high-density forms include the crystalline, amorphous and liquid phases with the former two being covalently bonded and semiconducting and the latter one metallic. At melting Si undergoes a semiconductor-metal transition along with a density increase of $\approx 10\%$ and significant changes in the local atomic struc-

ture. This evolves from an open one, with a tetrahedral fourfold coordination, to a more compact liquid structure with a white-tin-type arrangement preserving the local tetrahedrality and with an approximate sixfold coordination.^{16,17}

Most theoretical studies on l-Si have focused on its static structural properties and have resorted to classical MD simulations in which the liquid system was characterized by effective interatomic potentials constructed either empirically by fitting to experimental data^{2,3}, or derived from some approximate theoretical model.^{4,5,6} More recently, some KS-AIMD calculations^{7,8,9} have been reported, although the results dealt with electronic and static properties only because of the computational constraints inherent in this method.

Stich *et al*⁷ performed the first KS-AIMD calculation for l-Si near the triple point using 64 particles, a non-local Bachelet-Hamann-Schluter type pseudopotential¹⁸ and the local density approximation (LDA) for the electronic exchange and correlation energies. Subsequently, a more comprehensive study was performed⁸ with a larger number of atoms (350 particles) and a spin dependent generalized gradient approximation for electron exchange and correlation. A KS-AIMD calculation has also been performed by Chelikowsky *et al*⁹ using 64 atoms and a non-local, Troullier-Martins type, pseudopotential¹⁹ These *ab-initio* studies have provided accurate descriptions of the local liquid structure and valuable insights into the the valence electron charge densities, but, by necessity, they were too short to address dynamical properties (besides the self-diffusion coefficient) and these properties will now be the main focus of the present report which, to our knowledge, is the first *ab-initio* study on the dynamical properties of l-Si.

The static structure factor, $S(q)$, of l-Si has been measured by both neutron scattering (NS)¹⁰ and X-ray (XR)^{11,12,13} diffraction. Although all experimental $S(q)$'s show a distinctive shoulder at the high- q side of the main peak, there are some discrepancies in the positions and

heights of the first peak, its shoulder and the second peak. Experimental investigations of the dynamic structure of l-Si have been hampered by the large adiabatic sound speed (≈ 4000 m/s), which prevents the use of the inelastic thermal neutron scattering (INS) technique for investigating the collective excitations for small q -values. Nevertheless, the dynamical structure of l-Si near the triple point has been investigated recently by Hosokawa *et al*^{14,15} using high-resolution inelastic X-ray scattering (IXS) which has no such kinematic restrictions. The measurements by Hosokawa *et al* investigated the wavevector regions $0.02 \text{ \AA}^{-1} \leq q \leq 1.3 \text{ \AA}^{-1}$ [14] and $0.02 \text{ \AA}^{-1} \leq q \leq 2.96 \text{ \AA}^{-1}$ [15] and several dynamical features already observed in the liquid alkali metals were found, such as the existence of collective excitations up to q -values around $0.5 q_p$ (where q_p is the main peak's position of $S(q)$), along with a positive dispersion in the adiabatic sound velocity with respect to the hydrodynamic value.

Section II contains a brief description of the orbital-free *ab-initio* molecular dynamics (OF-AIMD) method, and gives some technical details particularly on the electronic kinetic energy functional and the local pseudopotential used to characterize the ion-electron interaction. In section III we present and discuss the results of the *ab-initio* simulations for several static and dynamic properties which are compared with the available experimental data. Finally, conclusions are drawn and possible avenues for further study are suggested.

II. THEORY.

A liquid simple metal may be treated as a disordered array of N bare ions with valence Z , enclosed in a volume V , and interacting with $N_e = NZ$ valence electrons through an electron-ion potential $v(r)$. The total potential energy of the system can be written, within the Born-Oppenheimer approximation, as the sum of the direct ion-ion coulombic interaction energy and the ground state energy of the electronic system under the external potential created by the ions, $V_{\text{ext}}(\vec{r}, \{\vec{R}_i\}) = \sum_{i=1}^N v(|\vec{r} - \vec{R}_i|)$,

$$E(\{\vec{R}_i\}) = \sum_{i < j} \frac{Z^2}{|\vec{R}_i - \vec{R}_j|} + E_g[\rho_g(\vec{r}), V_{\text{ext}}(\vec{r}, \{\vec{R}_i\})], \quad (1)$$

where $\rho_g(\vec{r})$ is the ground state electronic density and $\vec{R}_i$ are the ion positions. According to DFT, the ground state electronic density, $\rho_g(\vec{r})$, can be obtained by minimizing the energy functional

$$E[\rho(\vec{r})] = T_s[\rho] + E_H[\rho] + E_{\text{xc}}[\rho] + E_{\text{ext}}[\rho] \quad (2)$$

where the terms represent, respectively, the electron kinetic energy, $T_s[\rho]$, of a non-interacting system of density

$\rho(\vec{r})$, the classical electrostatic energy of the electrons (Hartree term),

$$E_H[\rho] = \frac{1}{2} \int \int d\vec{r} d\vec{s} \frac{\rho(\vec{r})\rho(\vec{s})}{|\vec{r} - \vec{s}|}, \quad (3)$$

the exchange-correlation energy, $E_{\text{xc}}[\rho]$, for which we have used the local density approximation and finally, the electron-ion interaction energy, $E_{\text{ext}}[\rho]$, where the electron-ion potential has been characterized by a first principles local pseudopotential constructed within DFT²⁰.

$$E_{\text{ext}}[\rho] = \int d\vec{r} \rho(\vec{r}) V_{\text{ext}}(\vec{r}), \quad (4)$$

In the KS-AIMD method,¹ $T_s[\rho]$ is exactly evaluated by using a set of roughly N_e single particle orbitals, but at huge computational expense. In contrast, the OF-AIMD approach uses an approximate but explicit density functional for $T_s[\rho]$ so that the system is described in terms of the single function $\rho(\vec{r})$ replacing the large set of orbitals.^{1,20,21} Proposed functionals incorporate the von Weizsäcker term,

$$T_W[\rho(\vec{r})] = \frac{1}{8} \int d\vec{r} |\nabla \rho(\vec{r})|^2 / \rho(\vec{r}), \quad (5)$$

plus further terms chosen in order to reproduce correctly some exactly known limits. Here, we have used an average density model²⁰, where $T_s = T_W + T_\alpha$,

$$T_\alpha = \frac{3}{10} \int d\vec{r} \rho(\vec{r})^{5/3-2\alpha} \tilde{k}(\vec{r})^2 \quad (6)$$

$$\tilde{k}(\vec{r}) = (2k_F^0)^3 \int d\vec{s} k(\vec{s}) w_\alpha(2k_F^0|\vec{r} - \vec{s}|)$$

$k(\vec{r}) = (3\pi^2)^{1/3} \rho(\vec{r})^\alpha$, k_F^0 is the Fermi wavevector for mean electron density $\rho_e = N_e/V$, and $w_\alpha(x)$ is a weight function chosen so that both the linear response theory and Thomas-Fermi limits are correctly recovered. Further details are given in Ref. [20].

Another key ingredient of the energy functional is the local ionic pseudopotential, $v_{ps}(r)$, describing the ion-electron interaction. It has been constructed from first-principles by fitting, within the same $T_s[\rho]$ functional, to the displaced electronic density induced by an ion embedded in a metallic medium as obtained in a KS-DFT calculation. Further details are given in Ref. [20] and we merely note that the theoretical framework used in this study has provided an accurate description of several static and dynamic properties in the liquid Li, Mg, Al, Na-Cs and Li-Na systems^{20,22}.

III. RESULTS

OF-AIMD simulations have been performed for l-Si in a thermodynamic state characterized by the temperature $T = 1740$ K and ionic number density $\rho_i = 0.05551 \text{ \AA}^{-3}$ [11]. We have considered 2000 ions in a cubic cell with periodic boundary conditions. Given the ionic positions at time t , the electron energy functional is minimized with respect to $\rho(\vec{r}) = \psi(\vec{r})^2$, where $\psi(\vec{r})$ is a single *effective orbital* which is expanded in plane waves which are truncated at a cutoff energy, $E_{\text{Cut}} = 12.75$ Ryd. The energy minimization with respect to the Fourier coefficients of $\psi(\vec{r})$ is performed every ionic time step by using a quenching method which results in the ground state electronic density and energy. The forces on the ions are obtained from the electronic ground state via the Hellman-Feynman theorem, and the ionic positions and velocities are updated by solving Newton's equations, with the Verlet leapfrog algorithm with a timestep of 3.5×10^{-3} ps. In the simulations equilibration lasted 10 ps. and the calculation of properties was made averaging over 50 ps. For comparison we mention that the previous KS-AIMD simulations lasted for 1.2 ps. [7] 0.9 ps. [8] and 1.0 ps. [9], which underscores its limitations for dealing with the dynamical properties.

Several liquid static properties have been evaluated (pair distribution function, static structure factor and bond angle distribution) as well as various dynamic properties, both single-particle ones (velocity autocorrelation function, mean square displacement) and collective ones (intermediate scattering functions, dynamic structure factors, longitudinal and transverse currents). The calculation of the time correlation functions was performed by taking time origins every five time steps. Several of these functions also depend on wave vector, which for our isotropic system is a dependence on $q \equiv |\mathbf{q}|$ only.

A. Static properties.

The pair distribution function, $g(r)$, and the static structure factor $S(q)$ can both be obtained directly from the simulation. The latter is plotted in Fig. 1 along with the X-ray diffraction data of Waseda *et al*^{11,12} and the neutron data of Gabathuler and Steeb¹⁰.

The OF-AIMD $S(q)$ has a main peak at $q_p \approx 2.59 \text{ \AA}^{-1}$ with a distinctive shoulder at $\approx 3.20 \text{ \AA}^{-1}$, the second peak is at $\approx 5.65 \text{ \AA}^{-1}$ and the subsequent oscillations are rather weak. As noted earlier there are some discrepancies among the measured structures in q_p , $S(q_p)$, and the positions of the shoulder and the second peak. The experimental results for q_p range from $2.49 \text{ \AA}^{-1}$ [13] to $2.78 \text{ \AA}^{-1}$ [10], the position of the shoulder from $3.15 \text{ \AA}^{-1}$ [13] to $3.40 \text{ \AA}^{-1}$ [10], and the second peak's position from $5.53 \text{ \AA}^{-1}$ [13] to $5.70 \text{ \AA}^{-1}$ [10]. In all cases the smaller estimate is from Takeda's XR data¹³ and the larger from the NS data of Gabathuler and Steeb¹⁰. It is worth mentioning that the XR data by Waseda *et al*^{11,12}

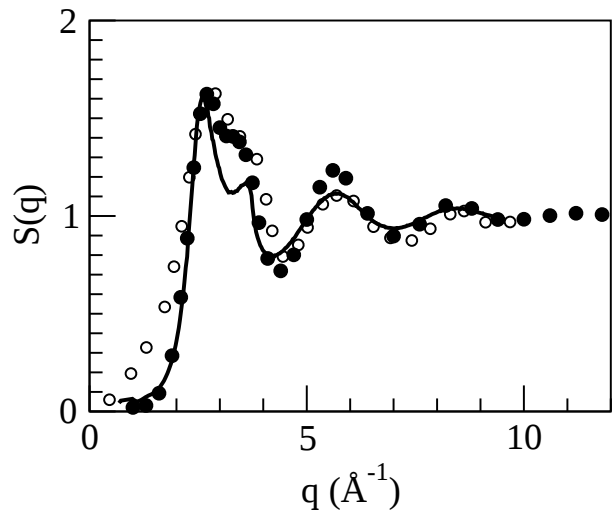


FIG. 1: Static structure factor of l-Si at 1740 K. Open circles: experimental NS data.¹⁰ Full circles: experimental XR data.^{11,12} Continuous line: OF-AIMD simulations.

gave values closer to the NS ones, namely $q_p = 2.76 \text{ \AA}^{-1}$ with the shoulder at $3.35 \text{ \AA}^{-1}$ and the second peak's position at $5.66 \text{ \AA}^{-1}$. Nevertheless, the values from the OF-AIMD simulation always lie within the range covered by the experimental data.

The OF-AIMD $S(q)$ accounts for the position and height of the main peak, although the amplitudes of the following peaks and troughs are somewhat underestimated. Moreover, the shoulder on the high- q side of the main peak, which is the most distinctive feature of the measured $S(q)$ for l-Si, is also reproduced by the simulation although with a smaller height. A similar shortcoming is visible in the $S(q)$ from the KS-AIMD simulations of Stich *et al*^{7,8}, whereas that of Chelikowsky *et al*⁹ gives a shoulder of similar height as the main peak.

Extrapolation of $S(q)$ to $q \rightarrow 0$ and use of the relation $S(0) = \rho_i k_B T \kappa_T$ gives an estimate for the isothermal compressibility κ_T . A least squares fit of $S(q) = s_0 + s_2 q^2$ to the calculated $S(q)$ for q -values up to $0.8 \text{ \AA}^{-1}$ yields $S(0) = 0.04 \pm 0.005$ and $\kappa_T = 3.0 \pm 0.6$ (in $10^{-11} \text{ m}^2 \text{ Nw}^{-1}$ units) for $T = 1740$ K. This latter value stands remarkably close to the experimental result²³ of $2.8 \times 10^{-11} \text{ m}^2 \text{ Nw}^{-1}$ and therefore provides confidence in the small- q behaviour of our calculated $S(q)$.

The simulation directly gives the pair distribution function, $g(r)$, whose main peak's position, r_p , is usually identified with the average nearest neighbor distance. The OF-AIMD simulation gives $r_p \approx 2.43 \text{ \AA}$, which is slightly smaller than the experimental data of $2.45 \text{ \AA}$ [11,12], $2.47 \text{ \AA}$ [13] and $2.50 \text{ \AA}$ [10]. An estimate of the number of nearest neighbors is obtained by integrating the radial distribution function (RDF), $4\pi r^2 \rho_i g(r)$, up to a distance r_m taken as the position of its first minimum^{24,25}; the present OF-AIMD study gives $r_m \approx 2.95 \text{ \AA}$, yielding to a coordination number of ≈ 6.0 atoms,

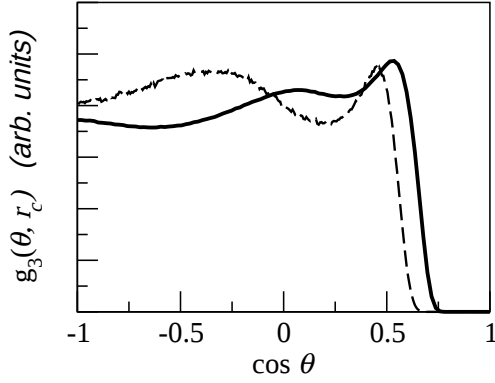


FIG. 2: Bond-angle distribution function, $g_3(\theta, r_c)$. The cut-off distance r_c is (a) the first minimum of the RDF, $r_c = 2.95$ Å (continuous line) and (b) the covalent cutoff $r_c = 2.49$ Å (dashed line).

which reasonably compares with the experimental values at $T=1735$ K ranging from ≈ 6.4 atoms¹¹ to ≈ 5.7 atoms¹³.

Signatures of possible remnants of covalent bonding that may remain in l-Si should be contained in higher order correlation functions. A convenient quantity is the bond-angle distribution function, $g_3(\theta, r_c)$, where θ is the angle between two vectors joining a reference particle with two neighboring particles at a distance less than r_c . In liquid simple metals, this function peaks at around $\theta \approx 60^\circ$ and 120° , which are close to those expected for a local icosahedral arrangement²⁶ ($\theta \approx 63.5^\circ$ and 116.5°). The OF-AIMD results for $g_3(\theta, r_c)$, with r_c taken as the first minimum of the RDF, are plotted in Fig. 2 where we see two maxima centered around $\theta \approx 60^\circ$ and 88° , which practically coincide with the values obtained from the KS-AIMD simulations^{7,8,9}, namely $\theta \approx 60^\circ$ and 90° . This double-peak feature has usually been interpreted as a signature of both tetrahedrally bonded and higher coordinated atoms contributing to the first coordination shell; indeed, according to Stich *et al*⁷ about 30% of the atoms in the first coordination shell are covalently bonded. Also plotted in Fig. 2 is the $g_3(\theta, r_c)$ with $r_c = 2.49$ Å which has been identified^{7,8} as the valence cutoff distance for covalent bonds. Now, the OF-AIMD results show a sharp maximum at $\theta \approx 65^\circ$ along with broader maximum centered around the tetrahedral angle $\theta \approx 109^\circ$. Summing up, the previous results emphasize the capability of the OF-AIMD method to account, albeit not so accurately as the KS-AIMD methods, for the orientational correlations in those liquid systems with some remnants of covalent bonding.

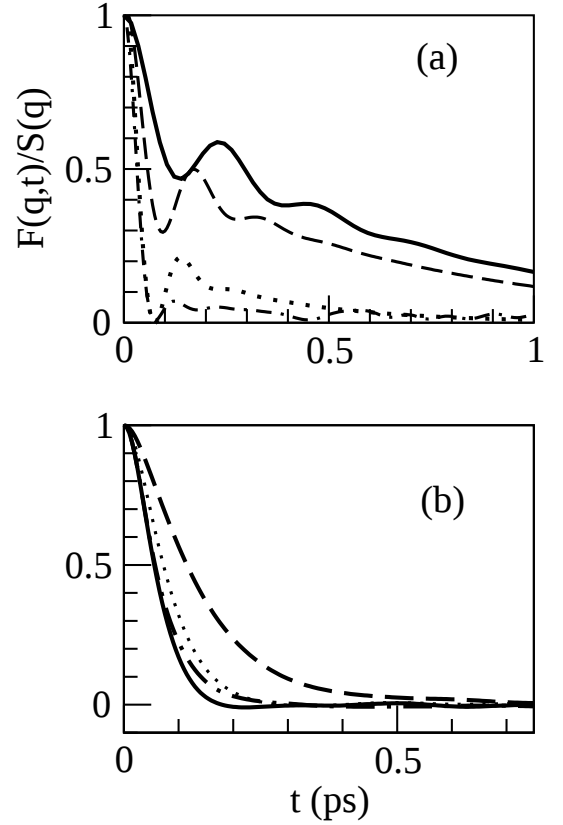


FIG. 3: Normalized intermediate scattering functions, $F(q, t)$, at several q -values (in Å⁻¹ units), for l-Si at $T = 1740$ K. (a) $q = 0.46$ (full line), $q = 0.72$ (dashed line), $q = 1.07$ (dotted line) and $q = 1.46$ (dot-dashed line). (b) $q = 2.0$ (full line), $q = 2.57$ (dashed line), $q = 3.0$ (dotted line) and $q = 3.62$ (dot-dash line).

B. Dynamic properties.

1. Collective dynamics.

The intermediate scattering function, $F(q, t)$, defined as

$$F(q, t) = \frac{1}{N} \left\langle \left(\sum_{j=1}^N e^{-i\vec{q}\vec{R}_j(t+t_0)} \right) \left(\sum_{l=1}^N e^{i\vec{q}\vec{R}_l(t_0)} \right) \right\rangle \quad (7)$$

contains spatial and temporal information on the collective dynamics of density fluctuations. Results for $F(q, t)$ as functions of time for several q -values are shown in Fig. 3. $F(q, t)$ oscillates up to $q \approx (3/5) q_p = 1.55 \text{ Å}^{-1}$, with the amplitude of the oscillations being stronger for the smaller q -values. This behaviour, which is plotted in Fig. 3(a), is typical of simple liquid metals near melting, as found from both computer simulations^{20,27,28,29} and theoretical models.³⁰ However, at low q -values ($q \leq 0.5 q_p$) the $F(q, t)$ shows a strong diffusive component which plays a dominant role and imposes a slow decay. This is at variance with the results for the simple liquid metals

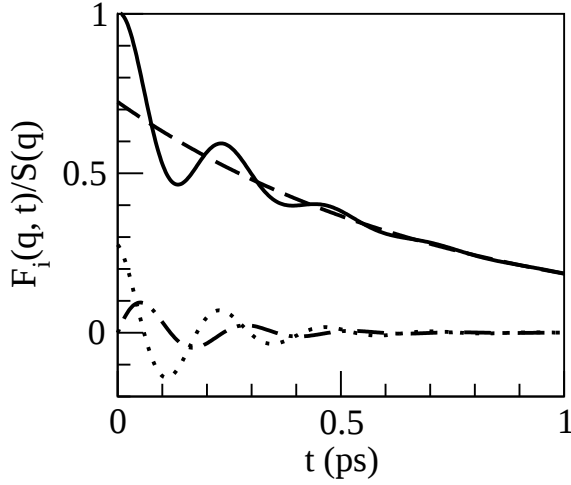


FIG. 4: Contributions to the $F(q, t)$ at $q = 0.47 \text{ \AA}^{-1}$ for l-Si at $T = 1740 \text{ K}$. Diffusive component (dashed line), cosine component (dotted line) and sine component (dash-dotted line).

near melting,^{20,27,28,29,30} where for a comparable q -range the diffusive component is already very weak and the corresponding $F(q, t)$ shows marked oscillations around zero.

This different behaviour can be explained in terms of the hydrodynamic expression for the $F(q, t)$, which is exact in the $q \rightarrow 0$ limit^{24,26} (hydrodynamic limit)

$$F(q, t)/S(q) = \left(\frac{\gamma - 1}{\gamma} \right) \exp(-D_T(q)t) + \frac{1}{\gamma} \exp(-\Gamma(q)t) [\cos(c_s q t) + b q \sin(c_s q t)] \quad (8)$$

and its time FT, the dynamic structure factor, $S(q, \omega)$,

$$2\pi S(q, \omega)/S(q) = \left(\frac{\gamma - 1}{\gamma} \right) \frac{2D_T(q)}{\omega^2 + (D_T(q))^2} + \frac{1}{\gamma} \left(\frac{\Gamma(q) + b q (\omega + c_s q)}{(\omega + c_s q)^2 + (\Gamma(q))^2} + \frac{\Gamma(q) + b q (\omega - c_s q)}{(\omega - c_s q)^2 + (\Gamma(q))^2} \right) \quad (9)$$

where $\gamma = C_p/C_v$ is the ratio of specific heats, c_s is the adiabatic sound velocity, $\Gamma(q) = \Gamma q^2$ with Γ the sound attenuation constant and $D_T(q) = D_T q^2$ where $D_T = \kappa_T/(\rho_i C_p)$ is the thermal diffusivity and κ_T is the thermal conductivity. Finally, $\Gamma = \frac{1}{2}[a(\gamma - 1)/\gamma + \nu_l]$ with $a = \kappa_T/(\rho_i C_v)$ and ν_l is the kinematic longitudinal viscosity.

According to Eq. (9), the hydrodynamic $S(q, \omega)$ has two (inelastic) propagating peaks centered at $\omega = \pm c_s q$ with half-width at half-maximum (HWHM), $\Gamma(q)$, and a diffusive peak at $\omega = 0$ and whose width is determined by the thermal diffusivity, D_T . For a metallic system, D_T has electronic and ionic contributions with the former dominating; however it has been shown³¹ that Eqs.

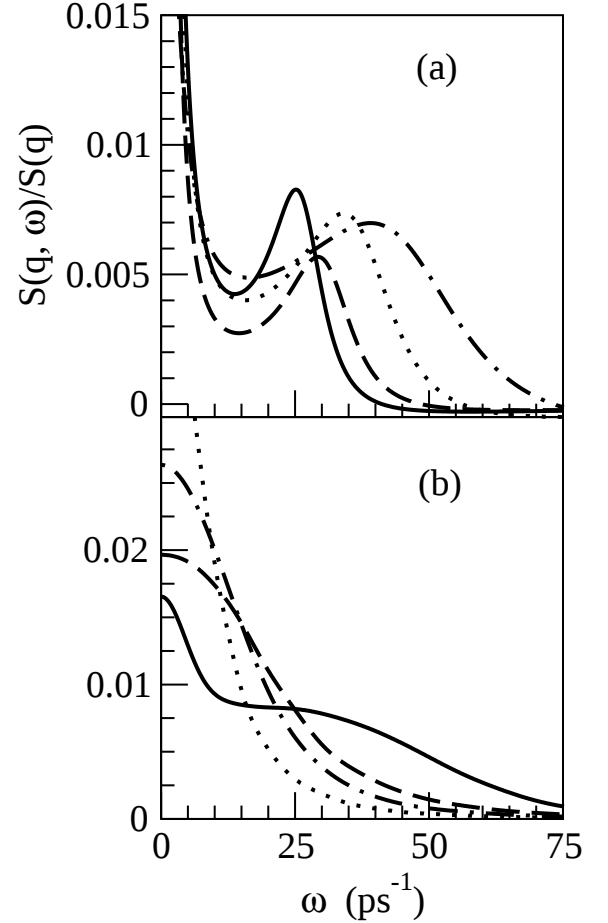


FIG. 5: Dynamic structure factor $S(k, \omega)$ at several q -values (in $\text{\AA}^{-1}$ units), for l-Si at $T = 1740 \text{ K}$. (a) $q = 0.46$ (full line), $q = 0.58$ (dashed line), $q = 0.72$ (dotted line) and $q = 1.07$ (dot-dashed line). (b) $q = 1.46$ (full line), $q = 2.00$ (dashed line), $q = 2.57$ (dotted line) and $q = 3.00$ (dot-dash line).

(8)-(9) incorporate just that part of D_T due to the ions. Consequently, we have fitted the OF-AIMD $F(q, t)$'s at the smallest q -values ($q \leq 0.6 \text{ \AA}^{-1}$), to the analytical expression of Eq. (8). A good fit was achieved in that q -range giving an approximate value $D_T \sim 1.0 \times 10^{-3} \text{ cm}^2/\text{sec.}$, which is two orders of magnitude smaller than the experimental one³² $D_T = 0.228 \pm 0.004 \text{ cm}^2/\text{sec.}$ for l-Si at melting, which obviously includes both ionic and electronic contributions. We note that an KS-AIMD study for liquid Ge near melting³¹ gave a comparable estimate of the ionic contribution, namely $D_T \sim 1.3 \times 10^{-3} \text{ cm}^2/\text{sec.}$, which is also two orders of magnitude smaller than its total D_T . On the other hand, estimates of the ionic contribution to D_T in the liquid alkali metals near melting³³ range from $20.0 \times 10^{-3} \text{ cm}^2/\text{sec.}$ (Li) to $3.0 \times 10^{-3} \text{ cm}^2/\text{sec.}$ (Cs). Consequently, as D_T determines the diffusive behaviour of the $F(q, t)$ at small q 's (see Fig. 4), the larger D_T values of the alkali metals imply a much weaker diffusive component which is easily overcome by

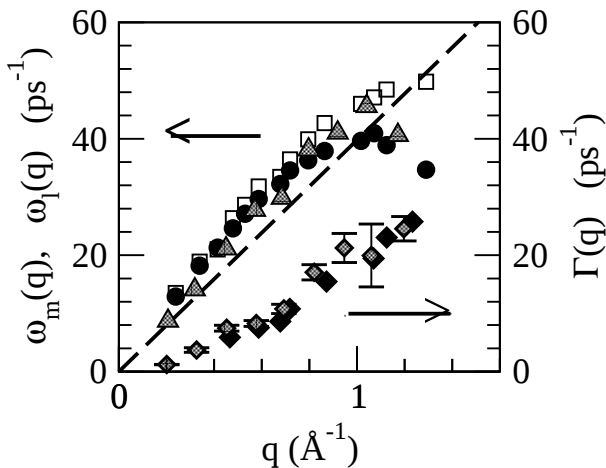


FIG. 6: Dispersion relation for l-Si at T=1740 K. Full circles: peak positions, $\omega_m(q)$, from the calculated $S(q, \omega)$. Triangles: experimental $\omega_m(q)$, from Hosokawa *et al* (Ref. 14). Open squares: peak positions, $\omega_l(q)$, from the maxima of the calculated longitudinal current, $J_l(q, \omega)$. Dashed line: Linear dispersion with the hydrodynamic sound velocity, $v=3977$ m/s. Grey (full) diamonds with error lines: experimental (calculated) values for the HWHM, $\Gamma(q)$, of the inelastic peaks.

the oscillatory parts of the $F(q, t)$.

$S(q, \omega)$, which is the quantity directly obtained from INS or IXS experiments, has been obtained by a time FT of the $F(q, t)$ and Fig. 5 shows several $S(q, \omega)$ as functions of ω for different wavevectors up to $\approx 1.2 q_p$. The $S(q, \omega)$ show well defined sidepeaks, indicative of collective density excitations, up to $q \approx (3/5) q_p$ which is also a common feature of the liquid simple metals^{20,26}.

The dispersion relation of the density fluctuations, $\omega_m(q)$, has been obtained from the positions of the sidepeaks of $S(q, \omega)$, and is shown in Fig. 6, along with $\omega_l(q)$, which is the dispersion relation obtained from the maxima of the longitudinal current correlation function, $J_l(q, \omega) = \omega^2 S(q, \omega)$. Figure 6 also includes the experimental $\omega_m(q)$ data of Hosokawa *et al*¹⁴ and a line representing the dispersion of the hydrodynamic sound whose slope gives the experimental³⁴ adiabatic sound velocity $c_s = 3977$ m/s at T=1753 K. The experimental $\omega_m(q)$ data has a *positive dispersion*, i.e. an increase of $\omega_m(q)$ with respect to the linear hydrodynamic dispersion relation value, with a maximum located around $0.8 \text{ \AA}^{-1}$ and whose magnitude amounts to $\approx 15\%$. Although there is fair agreement between our calculated $\omega_m(q)$ dispersion relation and experiment, the uncertainty at the small q -values prevents us from unequivocally declaring positive dispersion. A similar *positive dispersion* has been experimentally observed in the liquid alkali metals^{35,36,37}, Mg³⁸, Al³⁵ and Hg³⁹. On the other hand, we recall that at the hydrodynamic region, the slope of the dispersion relation curve gives a q -dependent adiabatic sound velocity, $c_s(q)$, which in the limit $q \rightarrow 0$ reduces to the bulk adiabatic sound velocity.

Another quantity characterizing the collective density excitations is the HWHM, $\Gamma(q)$, proportional to the inverse lifetime of the excitations. Figure 6 shows the experimental data for $\Gamma(q)$, which at low q values is $\propto q^2$ (hydrodynamic limit) but departs from it as q increases^{14,15}. The figure also includes the $\Gamma(q)$ obtained from the simulation, which agrees fairly well with the experiment. In passing we note that to calculate $\Gamma(q)$, the $F(q, t)$ obtained from the simulation is fit to an eight-parameter analytical expression that interpolates among the ideal gas, viscoelastic and hydrodynamic models⁴⁰. This method allows the different contributions to $S(q, \omega)$ to be disentangled and gives an estimate of $\Gamma(q)$ which in the present calculations is within an error of $\approx 15\%$.

The transverse current correlation function, $J_t(q, t)$, is not associated with any measurable quantity and can only be determined from computer simulations. It provides information on the shear modes and its shape evolves from a gaussian, in both q and t , at the free particle ($q \rightarrow \infty$) limit, to a gaussian in q and exponential in t at the hydrodynamic limit ($q \rightarrow 0$), i.e.

$$J_t(q \rightarrow 0, t) = \frac{1}{\beta m} e^{-q^2 \eta |t| / m \rho_i}, \quad (10)$$

where η is the shear viscosity coefficient, $\beta = (k_B T)^{-1}$ and m is the atomic mass. In both the above limits $J_t(q, t)$ is positive, but at intermediate q -values there is usually a more complicated behavior with well-defined oscillations within a limited q -range^{20,26,41}. $J_t(q, t)$ as functions of time for l-Si have been obtained from the simulation and are shown in Figure 7 for several q -values up to q_p . The most striking feature is the extreme weakness of the oscillations around zero. This is in remarkable contrast to the enormous amount of MD results for different liquid systems such as hard sphere systems⁴¹, Lennard-Jones liquids^{26,41} and simple liquid metals^{20,26,29} near melting, where the $J_t(q, t)$ exhibit strong oscillations and the associated spectra, $J_t(q, \omega)$, have an inelastic peak which appears at low q -values and lasts for a finite q -range. Again, l-Si near melting shows a different behaviour with the corresponding $J_t(q, \omega)$, which is also plotted in Figure 7, exhibiting a monotonic decreasing behaviour at all q 's. Taking into account that the inelastic peak in the $J_t(q, \omega)$, is associated with propagating shear waves, the results above point to their absence in l-Si near melting.

An estimate of the shear viscosity coefficient, η , has been made from $J_t(q, t)$ as follows.^{20,42,43} The memory function representation of $J_t(q, t)$:

$$\tilde{J}_t(q, z) = \frac{1}{\beta m} \left[z + \frac{q^2}{\rho_i m} \tilde{\eta}(q, z) \right]^{-1}, \quad (11)$$

where the tilde denotes the Laplace transform, introduces a generalized shear viscosity coefficient, $\tilde{\eta}(q, z)$. The area under the normalized $J_t(q, t)$, gives $\beta m \tilde{J}_t(q, z = 0)$ from

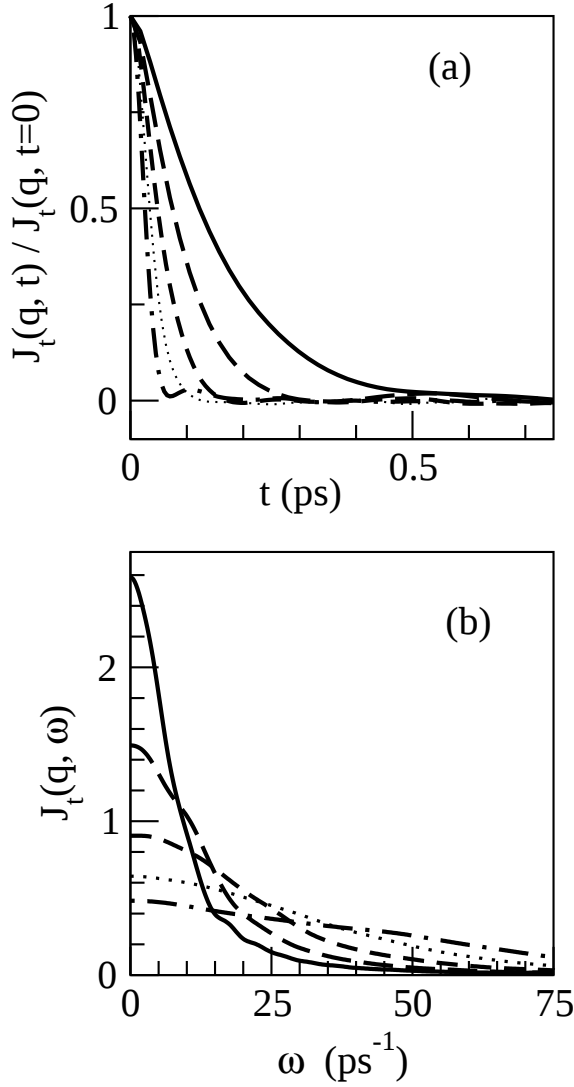


FIG. 7: (a) Transverse current correlation function $J_t(q, t)$ at several q -values (in $\text{\AA}^{-1}$ units), for l-Si at $T = 1740$ K. $q = 0.46$ (full line), $q = 0.72$ (long dashed line), $q = 1.07$ (short-dashed line), $q = 1.46$ (dotted line) and $q = 2.57$ (dash-dotted line). (b) Same for $J_t(q, \omega)$.

which values for $\tilde{\eta}(q, z = 0)$ can be obtained and these may be extrapolated to $q = 0$ to give the usual shear viscosity coefficient, η . The OF-AIMD simulations give $\eta = 0.75 \pm 0.1 \text{ GPa} \cdot \text{ps}$, which fairly compares with the available experimental results⁴⁴ $\eta_{exp} = 0.58\text{--}0.78 \text{ GPa} \cdot \text{ps}$.

2. Single-particle dynamics.

The most comprehensive information on the single-particle properties is provided by the self-intermediate scattering function, $F_s(q, t)$, which probes the single-particle dynamics over different length scales, ranging from the hydrodynamic to the free-particle limit. In the

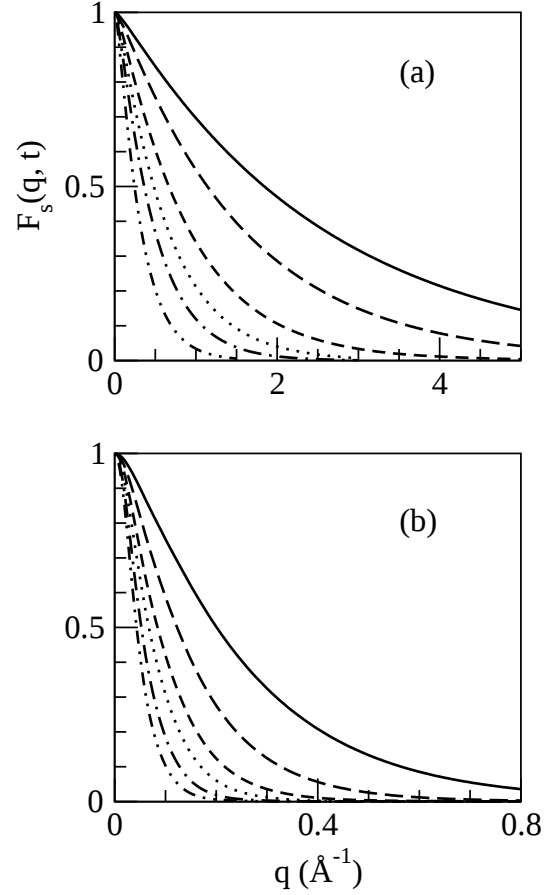


FIG. 8: Self intermediate scattering functions, $F_s(q, t)$, at several q -values (in $\text{\AA}^{-1}$ units), for l-Si at 1740 K. (a) $q = 0.42$ (full line), $q = 0.54$ (dashed line), $q = 0.72$ (short dashed line), $q = 0.86$ (dotted line), $q = 1.02$ (dot-dash line) and $q = 1.29$ (doble dot-dashed line). (b) $q = 1.46$ (full line), $q = 2.0$ (dashed line), $q = 2.57$ (short dashed line), $q = 3.0$ (dotted line), $q = 3.6$ (dot-dash line) and $q = 4.2$ (doble dot-dashed line).

present simulations, this quantity has been obtained using

$$F_s(q, t) = \frac{1}{N} \left\langle \sum_{j=1}^N e^{-i\vec{q}\vec{R}_j(t+t_0)} e^{i\vec{q}\vec{R}_j(t_0)} \right\rangle \quad (12)$$

and Fig. 8 depicts the results obtained for several q -values. It shows the usual monotonic decay with time; but comparison with the liquid simple metals (i.e. alkali, alkali-earths, Al)^{20,26,30} near their triple point shows that at similar q/q_p values, the $F_s(q, t)$ for l-Si decays much faster. As explained later, this fast decay is related to the significantly greater self-diffusion coefficient in l-Si.

Closely related to $F_s(q, t)$ is the velocity autocorrelation function (VACF) of a tagged ion in the fluid, $Z(t)$, which can be obtained as the $q \rightarrow 0$ limit of the first-order memory function of the $F_s(q, t)$. However, in the present

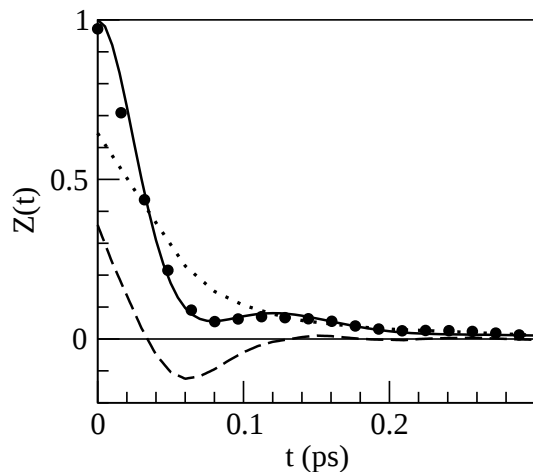


FIG. 9: Normalized OF-AIMD $Z(t)$ for l-Si at 1740 K (full line). The dashed and dotted lines are the longitudinal, $Z_l(t)$, and transverse, $Z_t(t)$, components respectively, as defined in Eq. (15), and the full circles represent their sum.

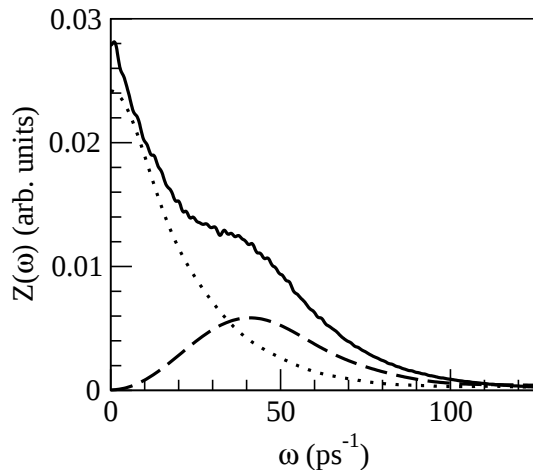


FIG. 10: Same as in the previous figure but for the corresponding power spectrum $Z(\omega)$.

simulations it is more easily obtained from its definition

$$Z(t) = \langle \vec{v}_1(t) \vec{v}_1(0) \rangle / \langle v_1^2 \rangle \quad (13)$$

Figures 9-10 show, respectively, the $Z(t)$ and its power spectrum $Z(\omega)$ obtained by taking the Fourier transform (FT) of the $Z(t)$. Besides the expected diffusive modes at low frequencies, the $Z(\omega)$ shows a shoulder at $\omega \approx 35 \text{ ps}^{-1}$, which is close to the optical vibrational frequency of covalent Si, and it has been related to the existence of vibrational modes echoing the remnant covalent bonds in the liquid⁷.

The $Z(t)$ shown in Fig. 9 lacks the usual backscattering behaviour observed in the liquid simple metals near melting which is usually ascribed to the so-called "cage

effect" due to the shell of nearest neighbors. The relatively open structure of l-Si with ≈ 6 nearest neighbors gives rise to a negligible "cage effect" and $Z(t)$ goes monotonically to zero. Indeed, its shape is remarkably similar to that from the KS-AIMD calculations of Stich *et al*^{7,8}. The self-diffusion coefficient, D , is readily obtained from either the time integral of $Z(t)$ or from the slope of the mean square displacement $\delta R^2(t) \equiv \langle |\vec{R}_1(t) - \vec{R}_1(0)|^2 \rangle$ of a tagged ion in the fluid, as follows

$$D = \frac{1}{\beta m} \int_0^\infty Z(t) dt ; \quad D = \lim_{t \rightarrow \infty} \delta R^2(t) / 6t \quad (14)$$

Both routes lead to practically the same value for $D_{\text{OF-AIMD}} = 2.28 \text{ \AA}^2/\text{ps}$. We know of no experimental results for the diffusion coefficients of l-Si at any thermodynamic state, but note that the KS-AIMD calculations of Stich *et al*^{7,8} gave $D_{\text{KS-AIMD}} = 2.02 \text{ \AA}^2/\text{ps}$, which slightly increased to $2.4 \text{ \AA}^2/\text{ps}$ when the number of particles was increased to 350 particles. They found⁸ that a spin dependent treatment of electron exchange and correlation within the GGA led to a further increase to $D_{\text{KS-AIMD}} = 3.1 \text{ \AA}^2/\text{ps}$, which was explained by a weakening of the interatomic bonds in comparison with the LDA treatment. The KS-AIMD study of Chelikowsky *et al*⁹ yielded $D_{\text{KS-AIMD}} = 1.90 \text{ \AA}^2/\text{ps}$. The present OF-AIMD result remains within the set of values predicted by the KS-AIMD method. Other calculations based on tight binding or interatomic pair potentials^{2,5,6} tend to produce significantly smaller values for the self-diffusion coefficient along with a VACF which takes negative values. We note that *ab-initio* estimates of the self-diffusion coefficient of l-Si are nearly one order of magnitude greater than corresponding ones for the liquid simple metals (alkalis, alkali-earths, Al) near melting^{20,45,46}. This larger D explains why $F_s(q, t)$ decays, for any q -value, much faster than in the simple liquid metals. The accurate gaussian approximation^{26,41} gives $F_s(q, t) = \exp[-q^2 \delta R^2(t)/6]$, and a greater D implies a larger $\delta R^2(t)$ and a faster decay for the $F_s(q, t)$.

With knowledge of the self-diffusion coefficient D and regarding the motion of an atom as the Brownian motion of a macroscopic particle of diameter d , the Stokes-Einstein (SE) relation, $\eta D = k_B T / 2\pi d$ can be used to obtain an estimate for the viscosity η . Identifying d with the position of the main peak of $g(r)$ as is commonly done gives $d = 2.40 \text{ \AA}$ and taking $D_{\text{OF-AIMD}} = 2.28 \text{ \AA}^2/\text{ps}$ leads to $\eta = 0.69 \text{ GPa} \cdot \text{ps}$ which is consistent with the previous OF-AIMD estimate obtained from the transverse current correlation function.

To achieve a deeper physical insight into the features of $Z(t)$, we resort to the mode-coupling (MC) approximation of Gaskell and Miller⁴⁷ which provides information about the relative importance of the coupling of the single-particle motion to the collective longitudinal and transverse currents. It has already been used to interpret MD data obtained for the VACF in Lennard-

Jones fluids, Yukawa fluids, alkali metals and even some molecular liquids^{47,48,49}. Within this approach

$$\begin{aligned} Z(t) &\approx \frac{1}{24\pi^3} \int d\mathbf{q} f(q) [J_l(q, t) + 2J_t(q, t)] F_s(q, t) \\ &\equiv Z_l(t) + Z_t(t) \end{aligned} \quad (15)$$

where $J_l(q, t)$ and $J_t(q, t)$ are the normalized longitudinal and transverse current correlation functions and

$$f(q) = \frac{3}{\rho_i} \frac{j_1(aq)}{aq} \quad (16)$$

where $j_1(x)$ is the spherical Bessel function of order one and a is an ionic radius given by $(4/3)\pi a^3 = 1/\rho_i$. Using the OF-AIMD results for $J_l(q, t)$, $J_t(q, t)$ and $F_s(q, t)$ in Eq. (15) allows the contributions of the longitudinal and transverse currents to be separated as $Z_l(t)$ and $Z_t(t)$ respectively. Firstly we note that, as shown in Fig. 9, the $Z(t)$ obtained by applying Eq. (15) is in excellent agreement with the $Z(t)$ given by the OF-AIMD simulation; therefore it may be reliably used to get deeper insight into the behavior of the $Z(t)$ by analyzing the separate contributions $Z_l(t)$ and $Z_t(t)$ to the integral (15).

These contributions to $Z(t)$ are plotted in Fig. 9 which shows that $Z_l(t)$ has some oscillatory behaviour, but $Z_t(t)$ remains positive for all times as a consequence of the mostly positive values taken by the $J_t(q, t)$'s (see Fig. 7). The positive bump of $Z(t)$ arises from the fast decay of $Z_l(t)$ which after a negative minimum at a rather short time (≈ 0.06 ps) quickly goes to zero. This behaviour, along with the comparatively slower decay of $Z_t(t)$ leads to the bump at ≈ 0.12 ps. At longer times, the dynamics of $Z(t)$ is completely determined by $Z_t(t)$. This shape has strong similarities with the MD simulation results for liquid water at room conditions⁴⁹, although the $Z(t)$ of l-Si always remains positive whereas in liquid water it takes negative values after the bump. However, in both systems the $Z(t)$ is strongly influenced by $Z_t(t)$. In contrast, the simple liquid metals show a very different pattern⁴⁷ with both $Z_l(t)$ and $Z_t(t)$ oscillating about zero. The $Z(t)$ also shows oscillations which, beyond the first minimum, are primarily determined by the $Z_l(t)$ which also dominates the large t behaviour of $Z(t)$.

The longitudinal and transverse components of the power spectrum are shown in Fig. 10. The small- ω behaviour is completely dominated by the $Z_t(\omega)$, whereas the shoulder in the $Z(\omega)$ is induced by the maximum in $Z_l(\omega)$ at $\omega \approx 40$ ps⁻¹. Note that the absence of a peak in $Z_t(\omega)$ can be traced back to the lack of inelastic peaks in $J_t(q, \omega)$ (see Fig. 7), which is in turn an expression of the failure of l-Si to sustain shear waves.

Again, there are substantial differences between the dynamical results for l-Si and those for liquid simple metals for which both $Z_t(\omega)$ and $Z_l(\omega)$ have clear maxima at ω_t^m and ω_l^m with $\omega_t^m \leq \omega_E \leq \omega_l^m$, where ω_E is the so-called "Einstein frequency" of the metal.²⁶ Consequently,

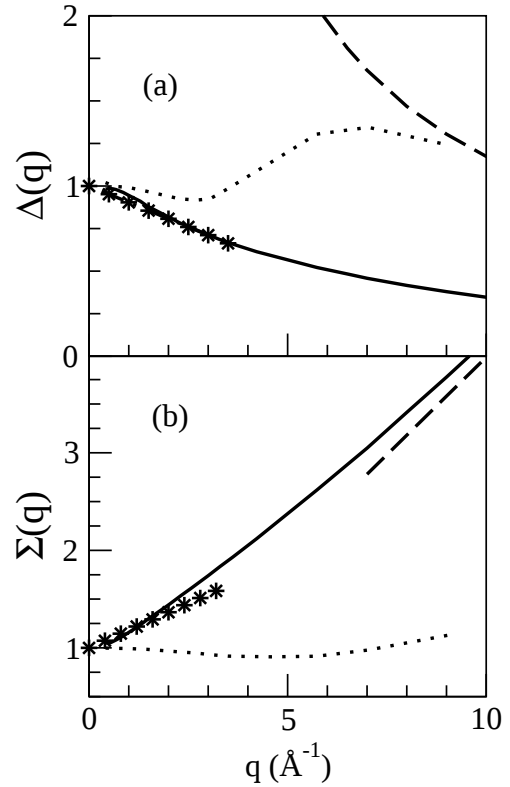


FIG. 11: (a) Normalized HWHM of $S_s(q, \omega)$, relative to its value at the hydrodynamic limit, for l-Si at $T = 1740$ K (continuous line) and liquid Al near melting (dotted line). The asterisks are the predictions of the mode-coupling theory and the dashed line gives the free-particle limit. (b) Same as above, but for the normalized peak value $S_s(q, \omega = 0)$, relative to its value at the hydrodynamic limit.

the $Z(\omega)$ for liquid metals usually has a maximum at $\approx \omega_t^m$ and a shoulder at $\approx \omega_l^m$ which, incidentally, is also the pattern exhibited by the MD results for liquid water⁴⁹. In their study of the $Z(t)$ for simple liquids⁴⁷, Gaskell and Miller, suggested that the appearance of a peak in $Z(\omega)$ at a frequency well below ω_E was indirect evidence that the liquid system can sustain the propagation of shear waves. The present results which show that l-Si lacks both the frequency peak and shear waves, are consistent with their suggestion. Finally, we note that the diffusion coefficient, which is proportional to $Z(\omega = 0)$, is completely determined by the transverse component which contributes $\approx 99\%$ of the total.

The time FT of $F_s(q, t)$ gives its frequency spectrum, $S_s(q, \omega)$, known as the self-dynamic structure factor, which has experimental importance due to its connection with the incoherent part of the INS cross-section. The $S_s(q, \omega)$ exhibits, for all q -values, a monotonic decay with frequency from a peak value at $\omega = 0$. Usually, $S_s(q, \omega)$ is characterized by the peak value, $S_s(q, \omega = 0)$, and the HWHM, $\omega_{1/2}(q)$, which are frequently reported normalized with respect to the values of the hydrodynamic (q

$\rightarrow 0$) limit, by introducing the dimensionless quantities $\Sigma(q) = \pi q^2 D S_s(q, \omega = 0)$ and $\Delta(q) = \omega_{1/2}(q)/q^2 D$. The OF-AIMD results for $\Delta(q)$ and $\Sigma(q)$ are shown in Fig. 11 along with OF-AIMD results for liquid Al for comparison. Both magnitudes exhibit a behaviour completely different from that of liquid Al which, in turn, stands as typical of the simple liquids near melting. Indeed, it has been found^{20,26,27} that liquid simple metals near their triple point have an oscillating $\Delta(q)$, stemming from the "cage effect", whereas for a dense gas it decreases monotonically from unity at $q=0$ to a $1/q$ behaviour at large q . The results for l-Si for both $\Delta(q)$ and $\Sigma(q)$ are more similar to those for a dense gas, which must be a consequence of the open structure. An indirect check on the reliability of these results may be provided by the MC theory^{50,51} which, has already shown its capability to account for the experimental $\Delta(q)$ and $\Sigma(q)$ in liquid simple metals^{52,53} at $q \leq q_p$. According to the MC theory

$$\begin{aligned}\Delta(q) &= 1 + H(\delta)q/q^* \\ \Sigma(q) &= 1 + G(\delta^{-1})q/q^*\end{aligned}\quad (17)$$

for small q -values, where $q^* = 16\pi m\rho_i\beta D^2$, $\delta = D/(D + \eta/m\rho_i)$ and the functions $H(\delta)$ and $G(\delta^{-1})$ are given in Ref. 52. In both equations the first term is the hydrodynamic result and the second one accounts for the coupling of mass diffusion with the collective modes. The OF-AIMD results for D and η have been used to determine $\Delta(q)$ and $\Sigma(q)$ given by Eq. (17) and the results are also shown in Fig. 11. For $q \leq q_p$ the OF-AIMD and MC theory results are in good agreement, similar to that found for simple metals. This agreement points to the ability of the MC theory to describe the single particle dynamics, and presumably the collective dynamics too, in l-Si.

IV. CONCLUSIONS.

Several static and dynamic properties of l-Si at a thermodynamic state close to the triple point have been evaluated. The simulations have been performed using the orbital free *ab-initio* molecular dynamics method combined with a first-principles local pseudopotential constructed within the same framework.

The results obtained for the static structure are comparable to those obtained by earlier KS-AIMD calculations^{7,8,9}, and are in reasonable agreement with the available experimental data. We also stress the good description provided by the OF-AIMD method for the orientational correlations, as described by the bond-angle distribution function, $g_3(\theta, r_c)$. The obtained structural magnitudes are in vein with other previous *ab-initio* studies which suggested for l-Si a local structure consisting in a mixture of both tetrahedrally bonded atoms and a higher coordinated structure (probably a distorted metallic white-tin structure). This latter assertion is based on

the idea¹⁶ that for non-close packed systems, the structure of the molten state resembles that of the high pressure solid state. If we now recall that in crystalline Si the semiconducting diamond structure contracts with pressure and transforms at 12 GPa to the metallic white-tin structure, this latter one looks as the most likely to be appear in l-Si.

Although the *ab-initio* methods based on the Kohn-Sham approach provide a deeper insight into those physical magnitudes related to bonding and electronic properties^{7,8}, their heavy computational demands have precluded their application to the study of the dynamic properties of liquids. Indeed, the calculation of the dynamical properties in l-Si has been the main aim of the present calculations which, incidentally were spurred by recent IXS data^{14,15}. Moreover, we stress that this is the first *ab-initio* study on the dynamical properties of l-Si.

The intermediate scattering functions, $F(q, t)$, have at low- q values, a strong diffusive component which is comparable to what has been found in liquid Ge, but is at variance with the liquid simple metals where the diffusive component is much weaker. The dynamic structure factors, $S(q, \omega)$, show collective density excitations over a similar range of wavelenths as those in liquid simple metals. Moreover, the dispersion relation of the excitations closely follows the existing experimental data^{14,15}.

The transverse current correlation functions, $J_t(q, t)$, show extremely weak oscillations around zero and take positive values for most of the time. This shape leads to spectra, $J_t(q, \omega)$, with no inelastic peaks which in turn reflect the absence of shear waves. This conclusion is reinforced by the analysis of the spectra of the VACF and appears as an effect of the low coordination number with its attendant negligible "cage effect". This is also reflected in the single particle dynamics, as embodied in the VACF and the self-intermediate scattering functions, leading to a behaviour different from that typical of the liquid simple metals near melting. Nevertheless, the MC theory appears capable of accounting for the single-particle dynamics in l-Si. Calculated self-diffusion and shear viscosity transport coefficients were in fair agreement with experiment and/or other *ab-initio* calculations.

Up to now, the OF-AIMD method has shown its ability to provide an accurate description of the bulk static and dynamic properties in simple liquid systems^{20,22}. However, the present results for the static and dynamic properties of l-Si illustrate the potential of the OF-AIMD method for treating liquid systems with remnants of covalent bonding and therefore open new venues concerning its range of applicability.

Acknowledgements

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S309(2004)